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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR **N0301N**

### N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

#### DESCRIPTION

The N0301N is a switching device which can be driven directly by a 4.0 V power source.

The N0301N features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

#### **FEATURES**

- 4.0 V drive available
- Low on-state resistance
- $\begin{array}{l} {\sf R}_{\sf DS(on)1} = 36 \mbox{ m}\Omega \mbox{ MAX.} \ ({\sf V}_{\sf GS} = 10 \mbox{ V}, \mbox{ I}_{\sf D} = 2.25 \mbox{ A}) \\ {\sf R}_{\sf DS(on)2} = 50 \mbox{ m}\Omega \mbox{ MAX.} \ ({\sf V}_{\sf GS} = 4.5 \mbox{ V}, \mbox{ I}_{\sf D} = 2.25 \mbox{ A}) \\ {\sf R}_{\sf DS(on)3} = 130 \mbox{ m}\Omega \mbox{ MAX.} \ ({\sf V}_{\sf GS} = 4.0 \mbox{ V}, \mbox{ I}_{\sf D} = 2.25 \mbox{ A}) \end{array}$
- Built-in gate protection diode

#### **ORDERING INFORMATION**

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
N0301N-T1-AT	Pure Sn (Tin)	Tape 3000 p/reel	SOT-23F

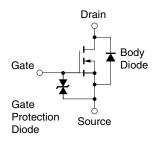
Marking: XU

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	VDSS	30	V
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V
Drain Current (DC) (T <sub>A</sub> = 25°C)	D(DC)	±4.5	А
Drain Current (pulse) <sup>Note1</sup>	D(pulse)	±18	А
Total Power Dissipation (T <sub>A</sub> = 25°C)	<b>P</b> T1	0.2	W
Total Power Dissipation $(T_A = 25^{\circ}C)^{Note2}$	Pt2	1.3	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

EQUIVALENT CIRCUIT

PACKAGE DRAWING (Unit: mm)

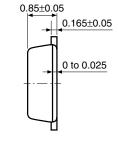


**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

- **2.** Mounted on FR-4 board of 50 mm  $\times$  50 mm  $\times$  1.6 mm, copper foil 100%, t  $\leq$  5 sec.
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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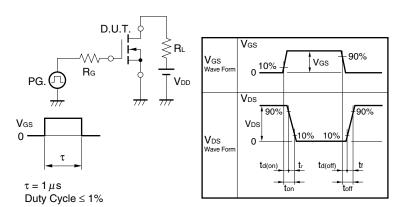
1: Source 2: Gate 3: Drain

ELECTRICAL CHARACTERISTICS (TA = 25°C)

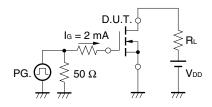
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			10	μA
Gate Leakage Current	Igss	$V_{GS}$ = ±16 V, $V_{DS}$ = 0 V			±10	μA
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA	1.0		2.5	V
Forward Transfer Admittance <sup>Note</sup>	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.25 A	2.0			S
Drain to Source On-state Resistance <sup>Note</sup>	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2.25 A		29	36	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 2.25 A		36	50	mΩ
	RDS(on)3	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 2.25 A		40	130	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V,		400		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		80		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		50		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 2.25 A,		6		ns
Rise Time	tr	V <sub>GS</sub> = 10 V,		4		ns
Turn-off Delay Time	$t_{d(\text{off})}$	R <sub>G</sub> = 10 Ω		23		ns
Fall Time	tr			4		ns
Total Gate Charge	QG	V <sub>DD</sub> = 24 V,		10		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V,		1.5		nC
Gate to Drain Charge	Qgd	I <sub>D</sub> = 4.5 A		2.5		nC
Body Diode Forward Voltage <sup>Note</sup>	VF(S-D)	IF = 4.5 A, VGS = 0 V		0.84		V
Reverse Recovery Time	Trr	IF = 4.5 A, VGS = 0 V,		20		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/ <i>µ</i> s		7		nC

Note Pulsed

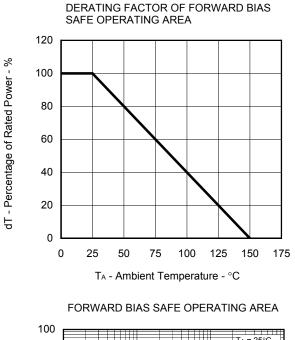
#### **TEST CIRCUIT 1 SWITCHING TIME**

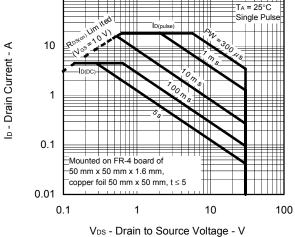


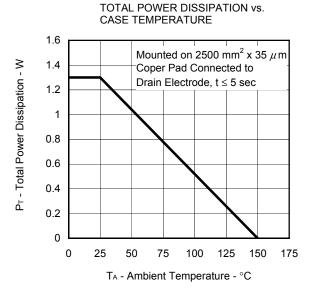
#### TEST CIRCUIT 2 GATE CHARGE



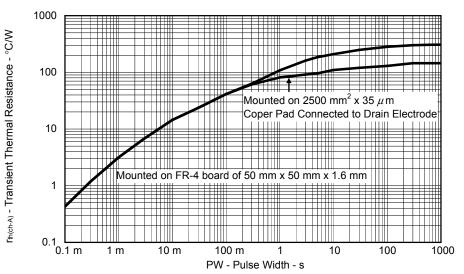
#### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



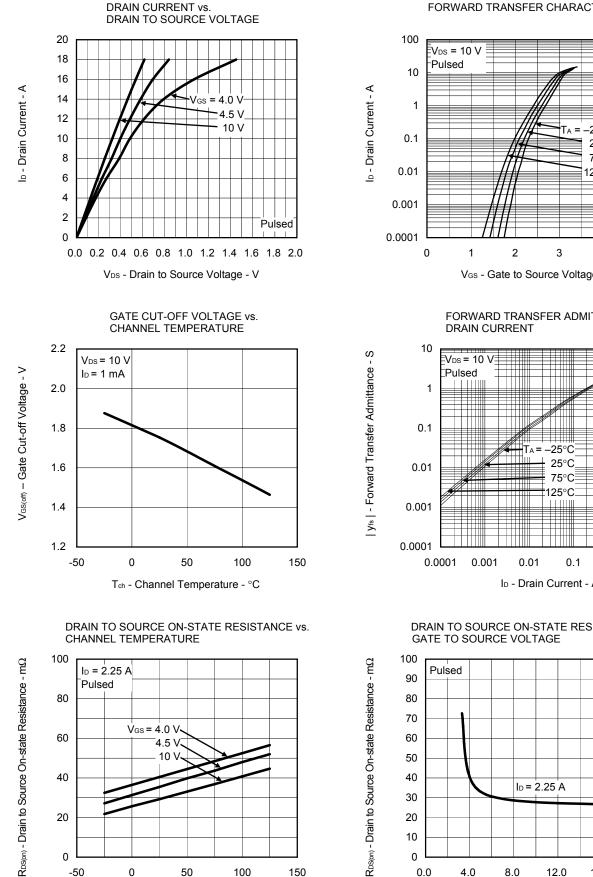




TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



Data Sheet D20202EJ1V0DS

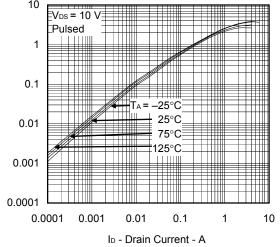


Tch - Channel Temperature - °C

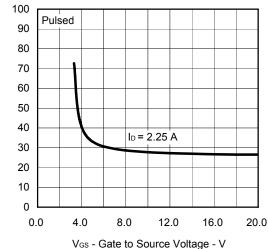
#### FORWARD TRANSFER CHARACTERISTICS

T<sub>A</sub> = -25°C 25°C 75°C 125°C₌ 4 5 VGS - Gate to Source Voltage - V

FORWARD TRANSFER ADMITTANCE vs.

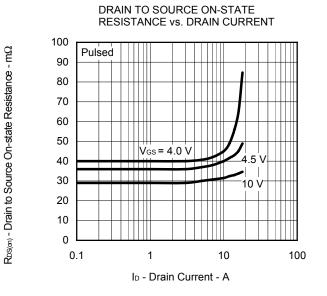


DRAIN TO SOURCE ON-STATE RESISTANCE vs.

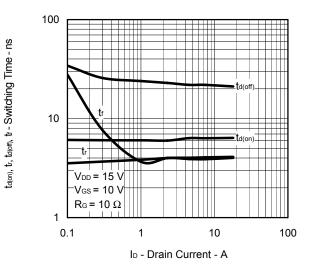


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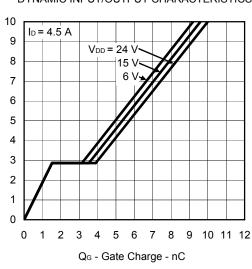


SWITCHING CHARACTERISTICS

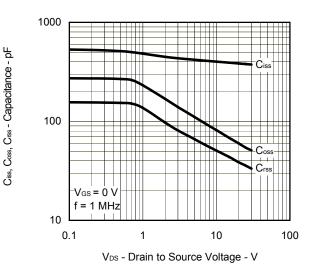


DYNAMIC INPUT/OUTPUT CHARACTERISTICS

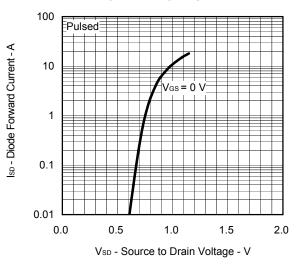
V<sub>GS</sub> - Gate to Drain Voltage - A



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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